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SLLS633C-OCTOBER 2004-REVISED NOVEMBER 2006

FEATURES

- Dual-Supply Operation . . . ±5 V to ±18 V
- Low Noise Voltage . . . 4.5 nV/√Hz
- Low Input Offset Voltage . . . 0.15 mV
- Low Total Harmonic Distortion . . . 0.002%
- High Slew Rate . . . 7 V/μs
- High-Gain Bandwidth Product . . . 16 MHz
- High Open-Loop AC Gain . . . 800 at 20 kHz
- Large Output-Voltage Swing . . . 14.1 V to –14.6 V
- Excellent Gain and Phase Margins

OUT1 1 8 V_{CC+} IN1- 3 6 N2V_{CC-} 4 5 N2+

DESCRIPTION/ORDERING INFORMATION

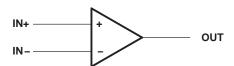
The MC33078 is a bipolar dual operational amplifier with high-performance specifications for use in quality audio and data-signal applications. This device operates over a wide range of single- and dual-supply voltages and offers low noise, high-gain bandwidth, and high slew rate. Additional features include low total harmonic distortion, excellent phase and gain margins, large output voltage swing with no deadband crossover distortion, and symmetrical sink/source performance.

ORDERING INFORMATION

T _A	PACKAGE	(1)	ORDERABLE PART NUMBER	TOP-SIDE MARKING(2)		
	PDIP – P Tube of 50		MC33078P	MC33078P		
	SOIC - D	Tube of 75	MC33078D	M22070		
-40°C to 85°C		Reel of 2500	MC33078DR	M33078		
	VSSOP/MSOP – DGK	Reel of 2500	MC33078DGKR	MV		
		Reel of 250	MC33078DGKT	MY_		

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

SYMBOL (EACH AMPLIFIER)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

⁽²⁾ DGK: The actual top-side marking has one additional character that designates the assembly/test site.

MC33078

DUAL HIGH-SPEED LOW-NOISE OPERATIONAL AMPLIFIER

SLLS633C-OCTOBER 2004-REVISED NOVEMBER 2006



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC+}	Supply voltage ⁽²⁾			18	V
V _{CC} -	Supply voltage ⁽²⁾			-18	V
$V_{CC+} - V_{CC-}$	Supply voltage		36	V	
	Input voltage, either input ⁽²⁾⁽³⁾	V	_{CC+} or V _{CC}	V	
	Input current ⁽⁴⁾		mA		
	Duration of output short circuit ⁽⁵⁾	Duration of output short circuit ⁽⁵⁾			
		D package		97	
θ_{JA}	Package thermal impedance, junction to free air (6)(7)	DGK package	172		°C/W
			85		
TJ	Operating virtual junction temperature		150	°C	
T _{stg}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the midpoint between \dot{V}_{CC+} and \dot{V}_{CC-} .
- 3) The magnitude of the input voltage must never exceed the magnitude of the supply voltage.
- (4) Excessive input current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs, unless some limiting resistance is used.
- (5) The output may be shorted to ground or either power supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.
- (6) Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (7) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

		MIN	MAX	UNIT
V _{CC} -	Supply voltage	- 5	-18	\/
V _{CC+}	Supply voltage	5	18	_ v
T _A	Operating free-air temperature range	-40	85	°C

SLLS633C-OCTOBER 2004-REVISED NOVEMBER 2006

DUAL HIGH-SPEED LOW-NOISE OPERATIONAL AMPLIFIER

Electrical Characteristics

 V_{CC-} = -15 V, V_{CC+} = 15 V, T_A = 25°C (unless otherwise noted)

	PARAMETER		ITIONS	MIN	TYP	MAX	UNIT		
V _{IO} Input offset voltage		$V_{O} = 0, R_{S} = 10 \Omega, V_{CM} = 0$		T _A = 25°C		0.15	2	mV	
*10	mpar onoor voltage	V0 = 0, 115 =	10 11, VCIVI — 0	$T_A = -40^{\circ}C$ to $85^{\circ}C$			3		
αV_{IO}	Input offset voltage temperature coefficient	$V_O = 0, R_S =$	10 Ω , $V_{CM} = 0$	$T_A = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C}$		2		μV/°C	
	Input higg ourrent	$V_{\rm O} = 0, V_{\rm CM}$	- 0	$T_A = 25^{\circ}C$		300	750		
I _{IB}	Input bias current	$v_O = 0, v_{CM}$	= 0	$T_A = -40^{\circ}C$ to $85^{\circ}C$			800	nA	
	Innut offeet ourrent	V 0 V	0	$T_A = 25^{\circ}C$		25	150	~ ^	
I _{IO} Input offset current		$V_O = 0, V_{CM} = 0$		$T_A = -40^{\circ}C$ to $85^{\circ}C$			175	nA	
V _{ICR}	Common-mode input voltage range	$\Delta V_{IO} = 5 \text{ mV},$	V _O = 0		±13	±14		V	
۸	Large-signal differential		140.1/	T _A = 25°C	90	110		dB	
A _{VD} voltage amplification	voltage amplification	$R_L \ge 2 k\Omega, V_O$	= ±10 V	$T_A = -40^{\circ}C$ to $85^{\circ}C$	85			uБ	
	Mariano	V _{ID} = ±1 V	R _L = 600 Ω	V _{OM+}		10.7			
				V _{OM} -		-11.9		V	
M				V _{OM+}	13.2	13.8			
V_{OM}	Maximum output voltage swing		$R_L = 2k \Omega$	V _{OM} -	-13.2	-13.7			
İ			P. – 10k O	V _{OM+}	13.5	14.1			
		$R_L = 10k \Omega$		V _{OM} -	-14	-14.6			
CMMR	Common-mode rejection ratio	$V_{IN} = \pm 13 \text{ V}$			80	100		dB	
k _{SVR} ⁽¹⁾	Supply-voltage rejection ratio	$V_{CC+} = 5 \text{ V to } 15 \text{ V}, V_{CC-} = -5 \text{ V to } -15 \text{ V}$			80	105		dB	
1	Output abort airquit aurrent	IV 1 = 1 V O:	italit to CND	Source current	15	29		mΛ	
Ios	Output short-circuit current	$ V_{ID} = 1 \text{ V, Output to GND}$		Sink current	-20	-37		mA	
1	Cupply ourrent (per phenoal)	V _O = 0		T _A = 25°C		2.05	2.5	- mA	
Icc	Supply current (per channel)			$T_A = -40^{\circ}C$ to $85^{\circ}C$			2.75		

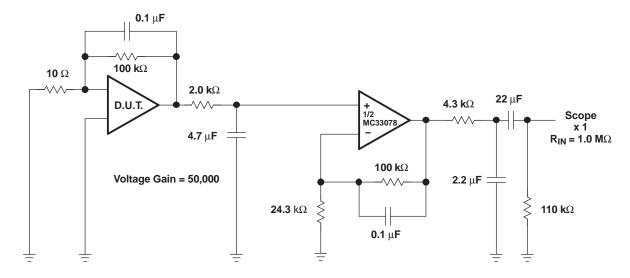
⁽¹⁾ Measured with $V_{\text{CC}\pm}$ differentially varied at the same time

Operating Characteristics

 V_{CC-} = -15 V, V_{CC+} = 15 V, T_A = 25°C (unless otherwise noted)

	PARAMETER	TEST (CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$A_{VD} = 1$, $V_{IN} = -10$ V to	10 V, $R_L = 2 k\Omega$, $C_L = 100 pF$	5	7		V/μs
GBW	Gain bandwidth product	f = 100 kHz		10	16		MHz
B ₁	Unity gain frequency	Open loop			9		MHz
(C-ii-	D 01:0	$C_L = 0 pF$		-11		dB
G _m	Gain margin	$R_L = 2 k\Omega$	C _L = 100 pF		-6		
4	Discouración	D 01:0	$C_L = 0 pF$		55		4
Φ _m P	Phase margin	$R_L = 2 k\Omega$	C _L = 100 pF		40		deg
	Amp-to-amp isolation	f = 20 Hz to 20 kHz	f = 20 Hz to 20 kHz				dB
	Power bandwidth	$V_O = 27 V_{(PP)}, R_L = 2 k\Omega$	$V_{O} = 27 V_{(PP)}, R_{L} = 2 k\Omega, THD \le 1\%$				kHz
THD	Total harmonic distortion	$V_{O} = 3 V_{rms}, A_{VD} = 1, R_{L}$	_ = 2 kΩ, f = 20 Hz to 20 kHz		0.002		%
Z _o	Open-loop output impedance	V _O = 0, f = 9 MHz	V _O = 0, f = 9 MHz				Ω
r _{id}	Differential input resistance	$V_{CM} = 0$		175		kΩ	
C _{id}	Differential input capacitance	$V_{CM} = 0$		12		pF	
V_n	Equivalent input noise voltage	$f = 1 \text{ kHz}, R_S = 100 \Omega$		4.5		nV/√ Hz	
In	Equivalent input noise current	f = 1 kHz		0.5		pA/√ Hz	





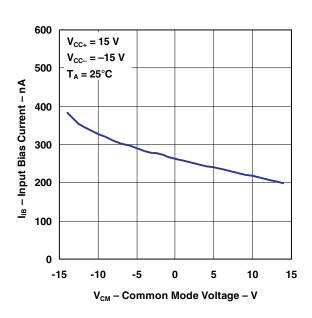
NOTE: All capacitors are non-polarized.

Figure 1. Voltage Noise Test Circuit (0.1 Hz to 10 Hz)

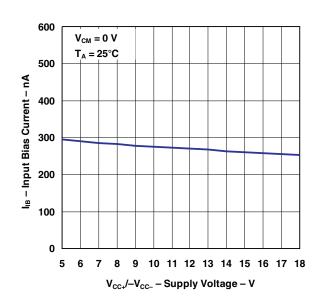


TYPICAL CHARACTERISTICS

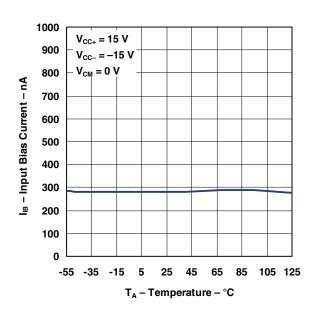
INPUT BIAS CURRENT vs COMMON-MODE VOLTAGE



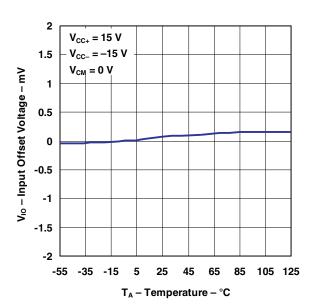
INPUT BIAS CURRENT VS SUPPLY VOLTAGE



INPUT BIAS CURRENT vs TEMPERATURE

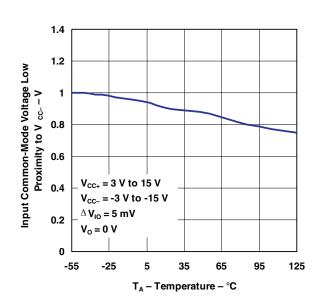


INPUT OFFSET VOLTAGE vs TEMPERATURE

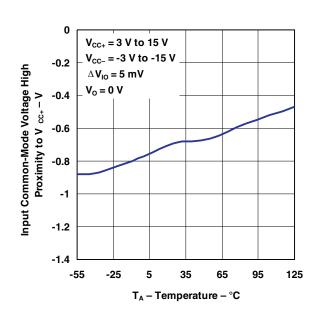




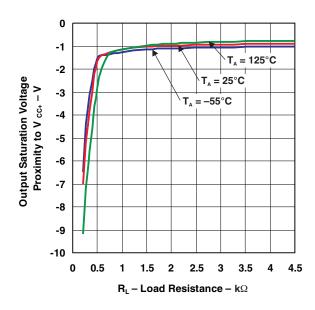




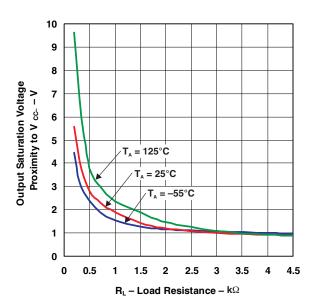
INPUT COMMON-MODE VOLTAGE HIGH PROXIMITY TO V_{CC+} vs TEMPERATURE



OUTPUT SATURATION VOLTAGE PROXIMITY TO V_{CC+} vs LOAD RESISTANCE

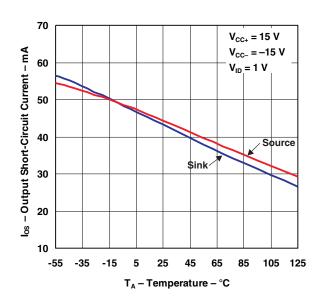


OUTPUT SATURATION VOLTAGE PROXIMITY TO V_{CC}-VS LOAD RESISTANCE

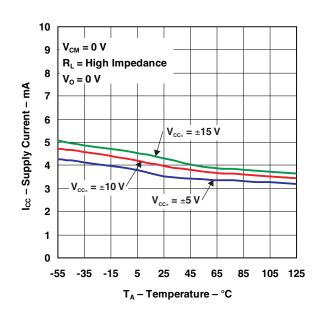




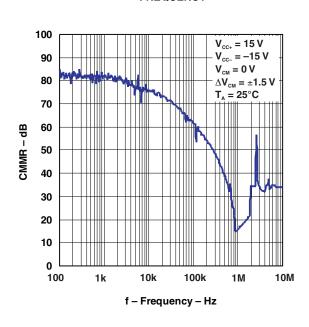
OUTPUT SHORT-CIRCUIT CURRENT vs TEMPERATURE



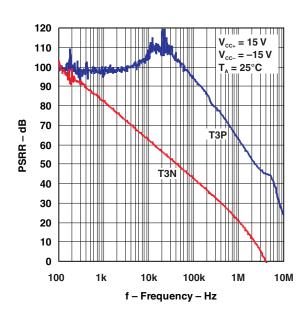
SUPPLY CURRENT vs TEMPERATURE



CMRR vs FREQUENCY

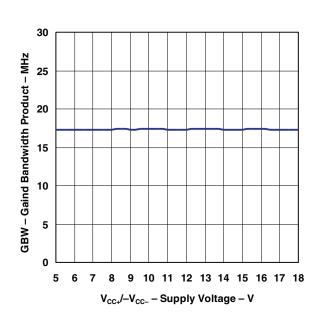


PSSR vs FREQUENCY

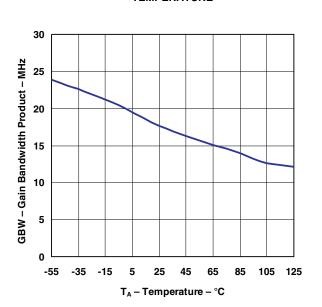




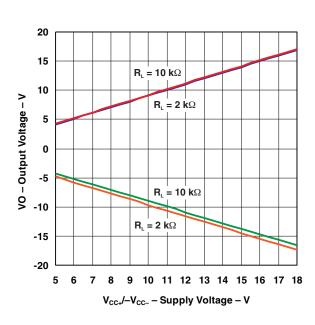
GAIN BANDWIDTH PRODUCT vs SUPPLY VOLTAGE



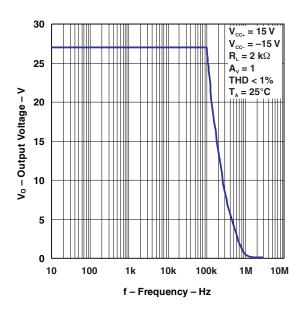
GAIN BANDWIDTH PRODUCT vs TEMPERATURE



OUTPUT VOLTAGE vs SUPPLY VOLTAGE



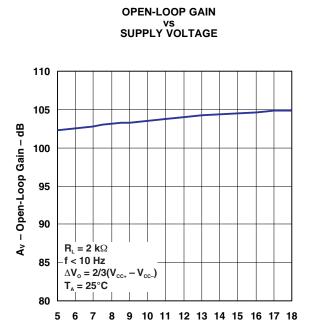
OUTPUT VOLTAGE vs FREQUENCY



OPEN-LOOP GAIN

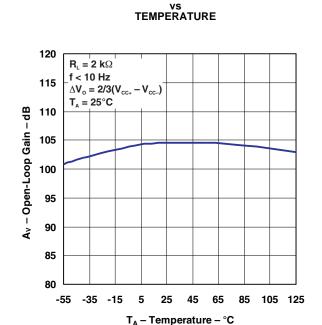


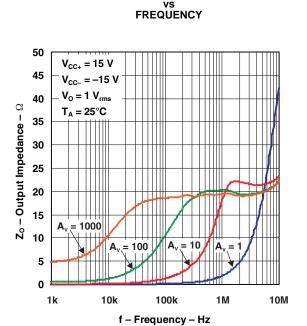
TYPICAL CHARACTERISTICS (continued)

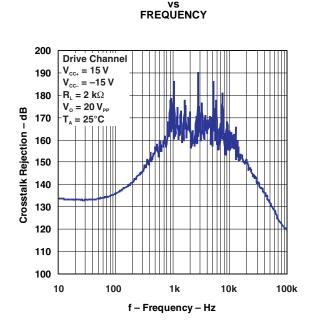


V_{cc+}/-V_{cc-} - Supply Voltage - V

OUTPUT IMPEDANCE



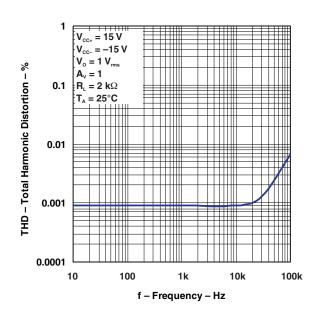




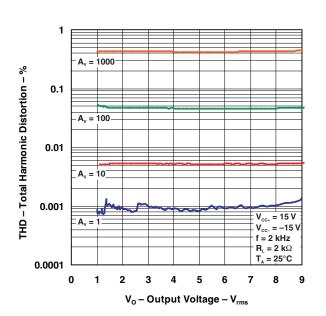
CROSSTALK REJECTION



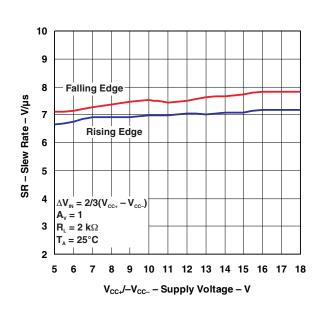
TOTAL HARMONIC DISTORTION VS FREQUENCY



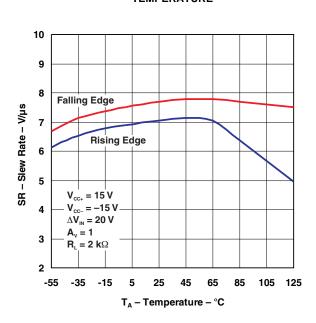
TOTAL HARMONIC DISTORTION VS OUTPUT VOLTAGE



SLEW RATE vs SUPPLY VOLTAGE

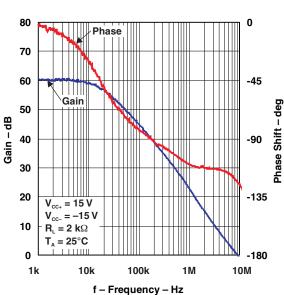


SLEW RATE vs TEMPERATURE

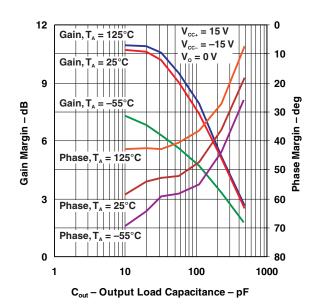




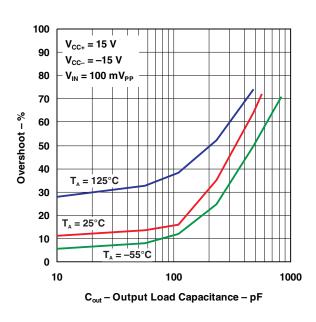




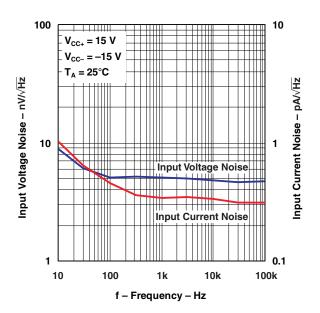
GAIN AND PHASE MARGIN
VS
OUTPUT LOAD CAPACITANCE



OVERSHOOT
vs
OUTPUT LOAD CAPACITANCE

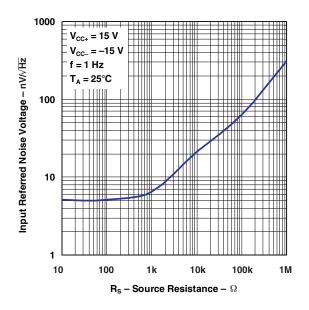


INPUT VOLTAGE AND CURRENT NOISE
vs
FREQUENCY

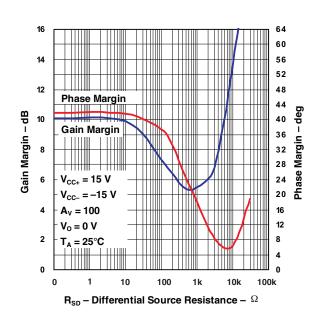




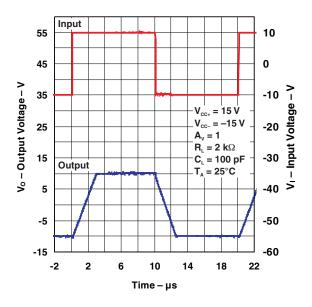
INPUT REFERRED NOISE VOLTAGE vs SOURCE RESISTANCE



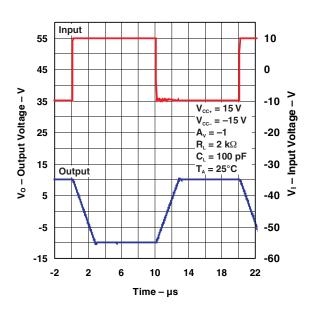
GAIN AND PHASE MARGIN vs DIFFERENTIAL SOURCE RESISTANCE



LARGE SIGNAL TRANSIENT RESPONSE (A_V = 1)

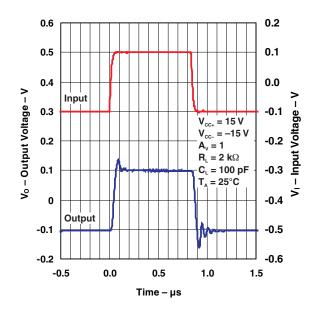


LARGE SIGNAL TRANSIENT RESPONSE $(A_V = -1)$

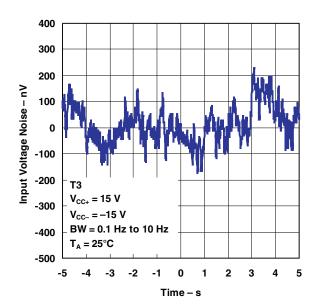




SMALL SIGNAL TRANSIENT RESPONSE



LOW_FREQUENCY NOISE





APPLICATION INFORMATION

Output Characteristics

All operating characteristics are specified with 100-pF load capacitance. The MC33078 can drive higher capacitance loads. However, as the load capacitance increases, the resulting response pole occurs at lower frequencies, causing ringing, peaking, or oscillation. The value of the load capacitance at which oscillation occurs varies from lot to lot. If an application appears to be sensitive to oscillation due to load capacitance, adding a small resistance in series with the load should alleviate the problem (see Figure 2).

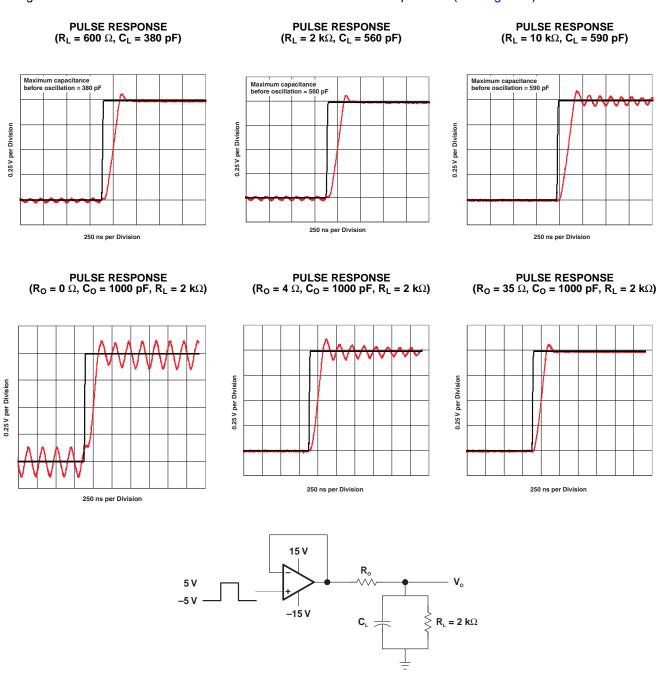


Figure 2. Output Characteristics



16-Aug-2012

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
MC33078D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
MC33078DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
MC33078DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
MC33078DGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
MC33078DGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
MC33078DGKT	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
MC33078DGKTG4	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
MC33078DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
MC33078DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
MC33078DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
MC33078P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
MC33078PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

16-Aug-2012

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF MC33078:

Enhanced Product: MC33078-EP

NOTE: Qualified Version Definitions:

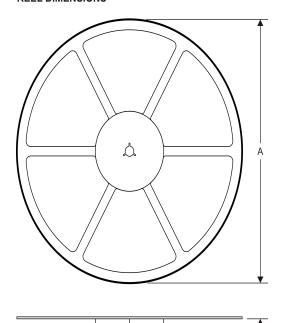
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

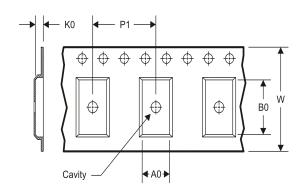
www.ti.com 16-Aug-2012

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MC33078DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
MC33078DGKT	VSSOP	DGK	8	250	180.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
MC33078DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
MC33078DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

www.ti.com 16-Aug-2012



*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MC33078DGKR	VSSOP	DGK	8	2500	346.0	346.0	35.0
MC33078DGKT	VSSOP	DGK	8	250	220.0	205.0	50.0
MC33078DR	SOIC	D	8	2500	367.0	367.0	35.0
MC33078DR	SOIC	D	8	2500	340.5	338.1	20.6

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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